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COMMUNICATION

Structure of the water-splitting photocatalyst oxysulfide α -LaOInS₂ and *ab initio* prediction of new polymorphs

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We unveil the structure and investigate the visible light water-splitting photocatalyst α -LaOInS₂, the second polymorph in this composition. This remarkable oxysulfide exhibits rare mixed anion InS₅O octahedra leading to both O-2p and S-3p hybridized with indium states in the vicinity of the Fermi level. *Ab initio* structure prediction shows the stability of such heteroleptic environments and points other hypothetical polymorphs.

Amidst oxychalcogenides, a large diversity of properties has been evidenced making them among the most promising candidates to design functional materials,¹ including those for sustainable energy.² However, they remain under-investigated compared with oxide solids. With their distinct anions exhibiting different radius and electronegativities, mixed anion compounds tend to offer low dimensional structures associated to anionic segregation into different layers³. As well illustrated for instance by Clarke *et al.*,⁴ this type of 2D-structuration can lead to original magnetic and electronic properties, for instance in the large family made of perovskite oxide blocks stacked with antifluorite type sulfide blocks.⁵ In addition, several wide band gap phases containing Cu-chalcogenide-layers such as Sr₂ZnO₂Cu₂S₂⁶ or LaOCuS⁷ may be doped to generate holes at the top of the valence band made of hybridized Cu 3d and S 3p states, leading to p-type conduction. While oxysulfides are increasingly investigated for a variety of properties (thermoelectricity⁸, superconductivity⁹, optical properties¹⁰ such as luminescence¹¹ ...), they also seem promising for photocatalysis^{12–13}. In particular, due to the different contributions to the valence band of several anions, *anionic*

band gap engineering should be possible in this way to design band gap tuned photocatalysts¹⁴.

Considering chalcogenides, they are attractive in that purpose compared to oxides as they can offer narrow band gap suitable for photocatalysis under visible-light irradiation, e.g. CuInS₂¹⁵. However, as pointed for instance by Wang *et al.*¹⁶ and ref. therein with sulfides the self-oxidation of sulfur anions competes with the oxidation reaction of water to produce O₂ resulting in non-stoichiometric water-splitting reactions. But this effect may be overcome with oxysulfides that are more stable. The same authors have recently shown the outstanding performances of Y₂Ti₂O₅S₂ oxysulfide (bandgap of 1.9 eV) as photocatalyst for overall water splitting under visible light and could optimize the conditions to obtain the concomitant and stoichiometric production of hydrogen and oxygen¹⁶. Few other oxychalcogenides systems have been pointed recently, such as LaOInS₂. The first phase identified with this composition, named hereafter α -LaOInS₂, was reported in 2004 with the unit cell parameters $a = 20.5421(6)$ Å, $b = 14.8490(4)$ Å and $c = 3.9829(1)$ Å in space group *Pbnm* obtained from a pure powder sample for which neither direct methods nor trial and error method enabled a structure determination¹⁷. Ogisu *et al.*¹⁸ have evidenced the visible light driven photocatalytic activity for overall water splitting of this sample following the synthetic method reported in ref. 17 while the structure remains unknown. They have also shown an enhancement of both O₂ and H₂ evolution using co-catalysts, IrO₂ and Pt respectively. More recently, another polymorph of LaOInS₂ with a band gap of 2.64 eV was reported with similar properties by Miura *et al.*¹⁹ on the basis of the structure initially targeted in ref. 17. Using the metathesis reaction LaOCl + NaInS₂ → LaOInS₂ + NaCl, they could successfully stabilize this metastable form composed by the stacking of alternating sulfide [InS₂] layers (rock-salt type) and oxide [LaO] layers (PbO-type). Here, we note the anionic segregation into different layers. Within the system La-O-In-S, the structure of the phases La₅In₃S₉O₃ (band gap ~ 2.60 eV)¹⁷ and La₁₀In₆S₁₇O₆²⁰ were also reported but were obtained in the

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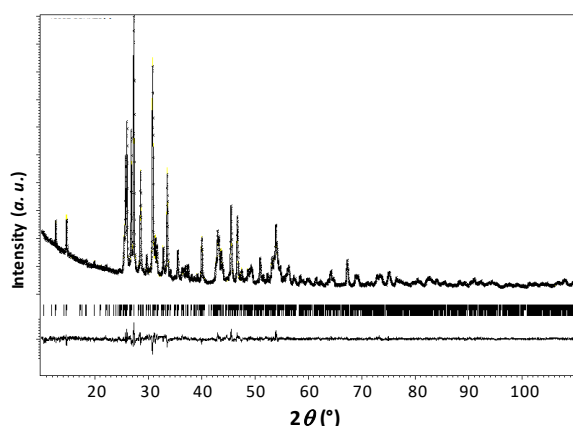
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form of single crystals only. In those phases and the elucidated LaOInS_2 , Indium is exclusively surrounded by sulfur.

In this article, we determine the structure of the unsolved polymorph $\alpha\text{-LaOInS}_2$ (with same composition but different structure) that proved visible light overall water splitting activity. The presence of a rare mixed anion environment (heteroleptic) in one Indium site InS_5O is discussed in relation with the DFT computed band gap features. Finally, using an Evolutionary Algorithm (EA) based code we propose new hypothetical structural models within the LaOInS_2 composition that exhibit heteroleptic environments. These results should



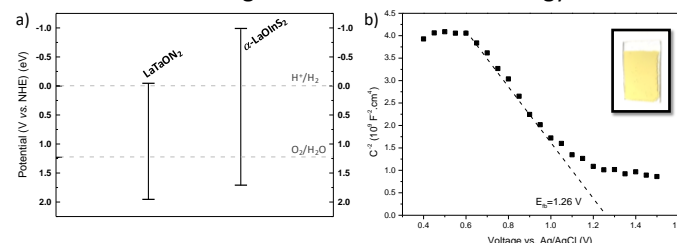
pave the way to the development of new functional candidates for visible light photocatalysis with tuned band gap.

Fig. 1 a) Powder XRD Rietveld refinement of $\alpha\text{-LaOInS}_2$

The powder synthesis of $\alpha\text{-LaOInS}_2$ phase was performed following the procedure described in the reference 17. The structure resolution was carried out from a high resolution powder XRD pattern with the refined unit cell parameters $a = 3.9850(2) \text{ \AA}$, $b = 20.5460(13) \text{ \AA}$ and $c = 14.8477(10) \text{ \AA}$ and the space group $Pm\bar{c}n$, equivalent to the unit cell in space group $Pbnm$ used for the profile fitting reported in 17. A structural model could be found using the charge flipping procedure of the SUPERFLIP program as implemented in the Jana2006 suite²¹. Then, Rietveld refinements combined with Fourier differences maps analysis were carried out to achieve a first structural model. At this stage, oxide anions were missing to reach the expected formulation LaOInS_2 . Based on the knowledge of related structures in the La-O-In-S phase diagram, we placed O3 in the La-O sub-lattice and performed a DFT full relaxation that led to a converged model. The relaxed position was then incorporated successfully in the experimental model to achieve a high quality Rietveld refinement with the reliability factors $R_{\text{obs}} = 0.0205$, $wR_{\text{obs}} = 0.0257$, $R_{\text{all}} = 0.0213$, $wR_{\text{all}} = 0.0258$ and $\text{GOF} = 1.54$, and Tables S2 and S3.

The photocatalytic activity was measured (see S1) for sake of comparison with the literature. The results (Fig. 3a) show greater detection in the presence of our catalyst and under a Xe lamp 100 W irradiation, which may be attributable to the H_2 production. We observe a reproducible behavior with an estimate of a H_2 production of $5.1 \mu\text{mol.h}^{-1}$. This result is fairly well correlated with the previously reported study on this phase¹⁸ and on the layered LaOInS_2 polymorph¹⁹. XPS analysis before/after the photocatalytic test proved a stable sample (see

S8). We have also estimated the band edge positions (Fig. 2a), as detailed in S7, which are encompassing the redox potentials of water as required to evolve hydrogen and oxygen. Moreover, a p-type semiconductor behavior is found from the Mott-Schottky (MS) plot (Fig. 2b) with a flat band potential E_{fb} estimated to 1.46 V (vs. NHE) in good agreement with the calculated VB band edge. Details of the methodology and more



discussion are in S9.

Fig. 2 a) Calculated band edges positions for the title phase $\alpha\text{-LaOInS}_2$ and for LaTaON_2 for comparison. The levels for hydrogen and oxygen evolution are indicated by dashed lines. b) Mott-Schottky plots for LaOInS_2 film deposited on ITO/Glass performed at 1 kHz.

The reported form of LaOInS_2 , in contrast with the title α phase, exhibits a simple layered structure that can be described by (LaO) and (InS_2) layers as mentioned in the introduction while the structures of $\text{La}_5\text{In}_3\text{S}_9\text{O}_3$ and $\text{La}_{10}\text{In}_6\text{S}_{17}\text{O}_6$ are more complex. They have been rationalized in reference 17 and are composed of NaCl-type slabs and fluorite-type ribbons alternating regularly with a corrugated sulfur monoatomic layer. Slight modifications of those building blocks imbrication are at the origin of the different structures and space groups.

The title phase $\alpha\text{-LaOInS}_2$ is unique in the La-O-In-S system as it shows a 3D structuration. It is constituted by the same basic units but differently imbricated. In particular, the fluorite type ribbons are alternating in different directions and the indium-based polyhedral network encircles them as highlighted on figure 3. In the La sublattice, La-O distances are in the range of 2.09–2.77 Å. For the shortest, Similar La-O distances are reported in La_3TaO_7 ^{22a} (with the shortest distances of 2.094 and 2.169 Å) or $\text{La}_4\text{Ti}_3\text{Fe}_{0.5}\text{Nb}_{0.5}\text{O}_{14}$ ^{22b} (La-O distances starting at 2.135 Å). Then, there are three different Indium sites In1–2–3, with the environments pictured on figure 3c and the distances detailed in table S4. InS_4 tetrahedra (Td) are found with In-S distances in the range ~ 2.244 to 2.664 \AA . This rather distorted Td with In^{3+} slightly off-centered from one S_3 face can be found in the layered LaOInS_2 but also in $\text{La}_5\text{In}_3\text{S}_9\text{O}_3$. On another hand InS_6 octahedra are found with $d_{(\text{In-S})} \sim 2.412$ – 2.718 \AA . More interestingly, the mixed anion octahedra InS_5O exhibits one $d_{(\text{In-O})} = 2.185 \text{ \AA}$ and three $d_{(\text{In-S})} \sim 2.392$ – 2.689 \AA with another set of two longer In-S distances of $2.9015(1) \text{ \AA}$. Considering the later heteroleptic coordination polyhedra might also be viewed as $Td+2$ rather than Oh . This heteroleptic oxide sulfide environment around indium is uncommon, it is for instance found in the unique phase $\text{Ba}_2\text{In}_2\text{Si}_3\text{O}_{10}\text{S}$ ²³ which exhibits original $[\text{In}_2\text{O}_7\text{S}_2]$ dimers made of face shared (InO_5S) and (InO_4S_2) heteroleptic octahedra. As discussed in the later reference, oxide halide mixed environments around Indium are common contrarily to oxide sulfide environments that constitute a peculiarity.

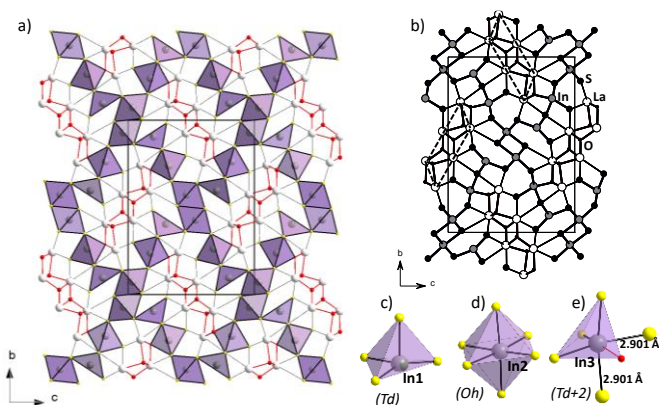


Fig. 3 Structure of LaOInS_2 a) with a polyhedral representation of the indium sub-lattice (purple) showing (PbO)-type units of 3-lanthanum width (light grey spheres) in a channel-like network made of interlinked In_1S_4 tetrahedron, In_2S_6 and $\text{In}_3\text{S}_5\text{O}$ octahedron (sulfur in yellow and oxygen in red); b) with a similar representation than found in ref. 17 and c-d-e) detailed environments around the different indium cations sites In_1 -2-3

The phonons calculations based on this structure are represented on Fig. 4b and clearly assess the stability of α - LaOInS_2 by the absence of negative frequencies. The density of states (DOS) are also reported in Fig. 4c. The observed band gap is underestimated compared to experience, but this is expected when using the widespread GGA-PBE functional. Here, we focus on a qualitative analysis of the valence band (VB) and of the conduction band (CB). The La 5p, 5d and 4f states are found with a large contribution of the empty 4f states around 4 eV in the CB. All these states are contributing at the top of the VB below -1 eV where they are hybridized with O 2p states (see O1). A very weak contribution of the La 6s states is observed. For Indium cations, In_1 -2-3 show similar topologies of their PDOS (see Fig. 4c and S15 with also the total DOS), with small differences such as for In_3 that exhibits a higher contribution around -3 eV where it hybridizes with O2 states not found for the other Indium cations that are exclusively surrounded by sulfur anions. More into details of In_3 , the states 5s are found at the bottom of the CB (together with the 5p states) and mainly between -5.6 eV and -4 eV in the VB. We note also a smaller contribution of the 4d states. The contribution of different anions surrounding the mixed anion $\text{In}_3\text{S}_5\text{O}$ octahedron, in particular O2, S6 (corner linking In_3 and In_1) and S5 pointing toward the lanthanum sub-lattice, is also highlighted on Fig. 4c. All contribute at the top of the valence band (VB) in the range of -5.6 eV to the Fermi level and to a lower extent at the bottom of the conduction band (CB). The maximum of the p states contributions is found with respect to the Fermi level as follow $\text{S5} \rightarrow \text{S6} \rightarrow \text{O2}$, O2 (2p) states lying deeper in the VB as expected from the electronegativities ($\chi_{\text{O}} = 3.44$ and $\chi_{\text{S}} = 2.58$) and the subsequent bonding character. A push down effect of oxygen compared to a sulfide In-S matrix may occur, leading to a slightly increased band gap considering sulfur based indium polyhedrons found in related phases, i.e. the layered LaOInS_2 . Here, we can highlight the band gap engineering potential of varying Indium environments in those systems.

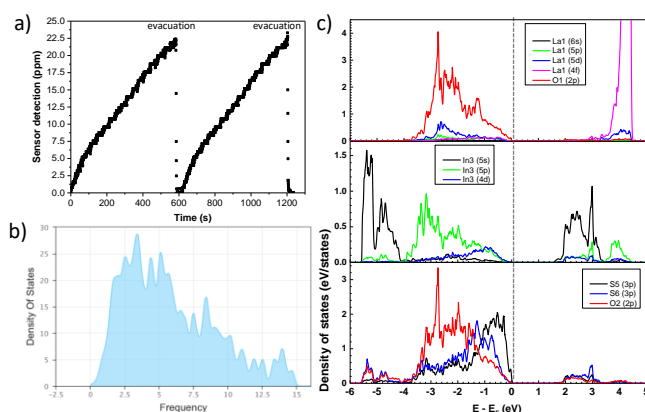


Fig. 4 a) Photocatalytic measurement of H_2 evolution, b) Phonons density of states and c) Projected Density of States (PDOS) for a selection of sites in α - LaOInS_2 with (from top to bottom) La1 states superposed with O1 2p states found in its environment, the heteroleptic In_3 (from $\text{In}_3\text{S}_5\text{O}$) and below, anions involved in the later, i.e. S5, S6 and O2 p states. The Fermi level is set to 0 eV (dashed line).

Stable structures in the LaOInS_2 composition were searched by using a first-principle EA implemented in the USPEX (Universal Structure Predictor: Evolutionary Xtallography) code²⁴. The structure prediction was carried out using the fixed composition LaOInS_2 and without restriction on the unit cell. The title phase has a large unit cell (~ 3 times larger than the volume of the EA phases calculated here) which is very difficult to investigate due to computational resources limitations. Therefore the experimental structure could not be found and the prediction led to alternative structures with much smaller volumes.

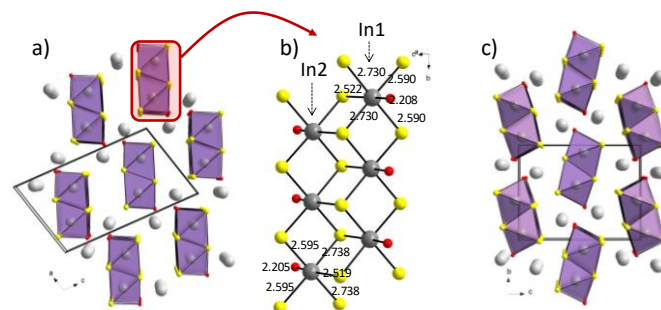


Fig. 5 Selection of structures predicted using the EA code a) the most stable one in $P2_1/m$. In b) details of the chain is shown (distances in Å) around the two Indium positions. c) The NCS structure in $P2_12_12_1$.

Here, the most stable structures reached in this way have very similar structures and differ from details of their symmetries. From the most energetically favorable to the least we have the symmetries $P2_1/m$ (-29.961 eV/FU) > $P2_1/c$ (-29.945 eV/FU) > $P2_12_12_1$ (-29.845 eV/FU) > $Pnma$ (-29.824 eV/FU). Then, we will go into more details of the most stable structure and the non-centrosymmetric one ($P2_12_12_1$) while crystallographic data for all the hypothetical structures are given in the SI. As shown on figure 5, they exhibit a 1D structuration with double-chains that are arranged in a parallel manner in the most stable phase and that are slightly tilted in the non-centrosymmetric phase. As highlighted in Fig. 5b, the most prominent feature of these chains is clearly that they are made of heteroleptic (exclusively)

InS₅O octahedra sharing edges which make them of great interest to pursue. This is clearly showing the strong stability of the mixed anion environment around Indium as discovered in the title phase α -LaOInS₂. With volumes per formula unit smaller than the title phase (comparing DFT relaxed data), they may be stabilize through alternative synthetic methods such as high pressure.

In this paper, we unveil the structure and investigate the oxysulfide α -LaOInS₂ within the remarkable La-O-In-S phase diagram. Although this system has been identified with an overall water splitting photocatalytic activity, the crucial structure investigation at the basis of the properties comprehension is achieved here. In particular, we observe the rare mixed anion InS₅O polyhedron. It leads to the contribution of both O 2p and S 3p hybridized with indium states below the Fermi level. As the photocatalytic activity relies on the states around the band gap, it should impact the activity compared to the reported cases where indium is in a mono-anionic environment such as in the layered LaOInS₂¹⁹ or CuInS₂¹⁵ for instance. In particular, it is proposed that oxysulfides should be more stable against sulfur self-oxidation during the O₂ evolution reaction; here sulfur and oxygen are mixed around the strategic cation. This point deserves further investigation to relate it to the properties and the stability for the design and elaboration strategies of new candidates. Finally, EA based structure prediction leads to exclusively mixed anion environments for Indium in smaller unit cells which suggests further promising systems to investigate experimentally.

Conflicts of interest

There are no conflicts to declare.

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